

# HTH7G14S150H(B) 150W, 1.8 - 1400 MHz LDMOS Amplifier

Product datasheet

#### **Description**

The HTH7G14S150H(B) is a unmatched discrete LDMOS Power Amplifier with 150W saturated output power covering frequency range from 1.8 - 1400 MHz.

#### **Features**

Operating Frequency Range: 1.8 - 1400 MHz

Operating Drain Voltage: 28-50V

• Saturation Output Power: 150W

• Internally Unmatched device

 Excellent thermal stability due to low thermal resistance package

Enhanced robustness design without device degradation

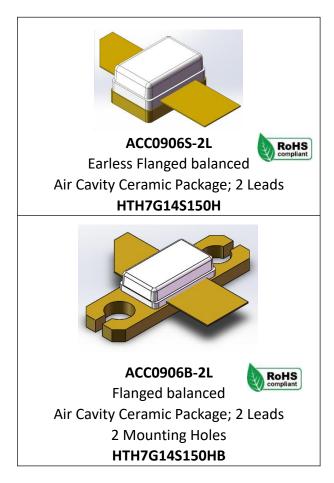
Internally integrated enhanced ESD design

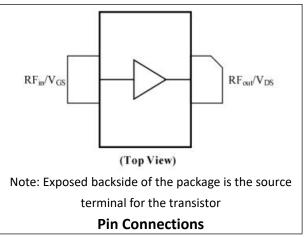
#### **Applications**

- Industrial, scientific, medical (ISM)
  - Laser generation
  - o Plasma generation
  - Particle accelerators
  - o MRI, RF ablation and skin treatment
  - Industrial heating, welding and drying systems

#### **Ordering Information**

| Part Number        | Description  |  |
|--------------------|--------------|--|
| HTH7G14S150H(B)    | Tray Package |  |
| HTH7G14S150H(B)EVB | 860 MHz EVB  |  |





# WATECH

**Typical Performance** 

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#### DE Characteristics (Dules d C

#### **RF Characteristics (Pulsed CW)**

| Freq (MHz) | P1dB (dBm) | P1dB (W) | Gain (dB) | Eff(%)@P3dB |
|------------|------------|----------|-----------|-------------|
| 860        | 52.0       | 158      | 21.5      | 56.0        |

Test conditions unless otherwise noted: 25 °C, VDD = +50Vdc, IDQ = 300mA, PW = 100us, DC = 10% test on WATECH Application Board

### **Absolute Maximum Ratings**

| Parameter                              | Range/Value  | Unit |
|--|--------------|------|
| Drain voltage (VDSS)                   | -0.5 to +105 | V    |
| Gate voltage (V <sub>GS</sub> )        | -5 to +10    | V    |
| Storage Temperature (Tstg)             | -55 to +150  | °C   |
| Junction Temperature (T <sub>J</sub> ) | -40 to +225  | °C   |

## **Electrical Specification**

#### **DC Characteristics**

| Parameter                   | Conditions         | Min | Тур | Max | Unit |
|-----------------------------|--------------------|-----|-----|-----|------|
| Breakdown Voltage V(BR)DSS  | Vgs=0V, Ids=100uA  | 105 | -   | -   | V    |
| Gate-Source Threshold       | Vds=Vgs, Ids=100uA | 1.2 | 2.0 | 2.8 | V    |
| Voltage V <sub>GS(th)</sub> | vus-vgs, ius-100uA | 1.2 | 2.0 | 2.0 | V    |
| Drain Leakage Current loss  | Vgs=0V, Vds=50V    | -   | -   | 10  | uA   |
| Gate Leakage Current IGSS   | Vgs=5V, Vds=0V     | -   | -   | 1   | uA   |

#### **Load Mismatch Test**

| Condition  | Test Result |
|--|-------------|
| VSWR=20:1 at all Phase Angles, VDD = +50Vdc, IDQ=300mA, Pout = 150W, | No Device   |
| PW = 200us, DC= 20%, freq@860 MHz                                    | Degradation |

#### **Thermal Information**

| Parameter              | Condition                         | Value (Typ) | Unit  |
|------------------------|-----------------------------------|-------------|-------|
| Thormal Bosistanso     | TFLANGE= 60°C, VDD = +50Vdc,      |             |       |
| Thermal Resistance     | IDQ=300mA, Pout= 52 dBm (150W),   | 0.8         | °C /W |
| Junction to Case (Rтн) | PW = 100us, DC= 10%, freq@860 MHz |             |       |

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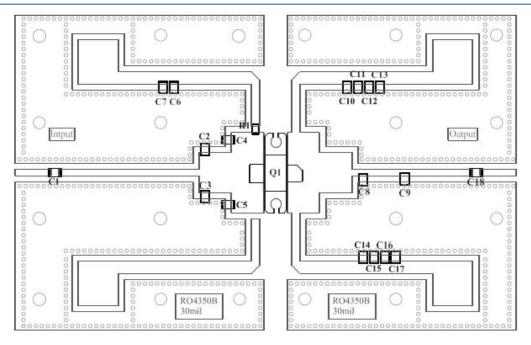


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#### HTH7G14S150H(B)

### 860 MHz Reference Design



**EVB Layout** 

## Bill of Materials (BoM) - HTH7G14S150H(B)

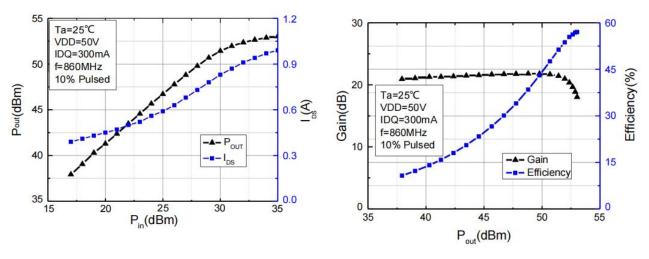
## 860 MHz Reference Design

| Reference                 | Value   | Description                      | Manufacturer | P/N                |
|---------------------------|---|----------------------------------|--------------|--------------------|
| Q1                        | -   | 150W, 1.8 - 1400 MHz<br>LDMOS PA | Watech       | HTH7G14S150H(B)    |
| C1, C6, C10,<br>C14, C18  | 56pF  | MLCC                             | ATC          | ATC100B560JT500XT  |
| C2                        | 6.8pF   | MLCC                             | ATC          | ATC100B6R8JT500XT  |
| C3                        | 8.2pF   | MLCC                             | ATC          | ATC100B8R2JT500XT  |
| C4, C5, C8                | 10pF  | MLCC                             | ATC          | ATC100B100JT500XT  |
| С9                        | 2.4pF   | MLCC                             | ATC          | ATC100B2R4JT500XT  |
| C11, C15                  | 10nF  | MLCC                             | Murata       | GR321AD72E103KW01D |
| C7, C12, C13,<br>C16, C17 | 10uF  | MLCC                             | Murata       | GRM32EC72A106KE05  |
| C19                       | 10uF  | MLCC                             | AVX          | 22201C106MAT2A     |
| R1,                       | 10Ω   | Thick Film Resistor              | YAGEO        | RC0805FR-0710RL    |
| PCB                       | Rogers4350B (er = 3.66), 30 mil (0.762 mm), 35 μm (1oz) |                                  |              |                    |

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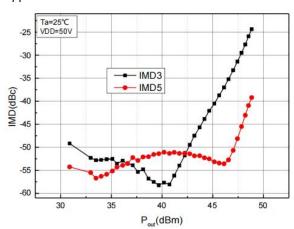
#### **Performance Plots**

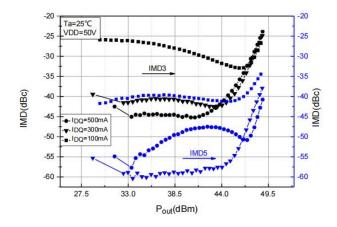


#### Pulsed CW, Pout vs Pin

#### Pulsed CW, Gain and Efficiency vs Pout

Test conditions unless otherwise noted: 25 °C, VDD = +50dc, IDQ = 300mA, PW = 100us, DC = 10% test on WATECH Application Board





Two Tone IMD vs Pout

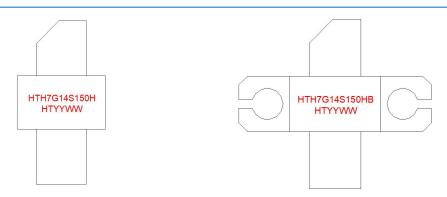
Two Tone IMD vs Pout @Idq's

Test conditions unless otherwise noted: 25 °C, VDD = +50Vdc, IDQ=300mA, Two tone Test, Carrier Spacing @600KHz test on WATECH Application Board

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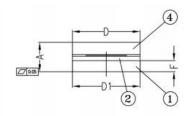
#### **Package Marking and Dimensions**

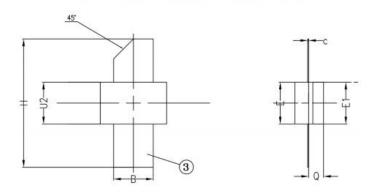


- Line1 (fixed): Device name in W/O
- Line2 (unfixed): HT+Date Code

This Marking SPEC only stipulates the content of Marking. For marking requirements such as font and size, please refer to the latest version of "Watech Product Printing Specification"

#### Marking





| Symbol | Dimens | Dimensions In Millimeters |       | Dime  | nsions In I | nches |
|--------|--------|---------------------------|-------|-------|-------------|-------|
| Min.   | Min.   | Mon.                      | Max.  | Min.  | Mon.        | Max.  |
| Α      | 3.84   | 3.98                      | 4.12  | 0.151 | 0.157       | 0.162 |
| В      | 5.37   | 5.50                      | 5.63  | 5.211 | 0.217       | 0.222 |
| С      | 0.11   | 0.13                      | 0.15  | 0.004 | 0.005       | 0.006 |
| D      | 9.07   | 9.20                      | 9.33  | 0.357 | 0.362       | 0.367 |
| D1     | 9.07   | 9.20                      | 9.33  | 0.357 | 0.362       | 0.367 |
| E      | 5.67   | 5.80                      | 5.93  | 0.223 | 0.228       | 0.233 |
| E1     | 5.67   | 5.80                      | 5.93  | 0.223 | 0.228       | 0.233 |
| F      | 1.37   | 1.50                      | 1.63  | 0.054 | 0.059       | 0.064 |
| Н      | 17.30  | 17.80                     | 18.30 | 0.681 | 0.701       | 0.720 |
| Q      | 1.95   | 2.08                      | 2.21  | 0.077 | 0.082       | 0.087 |
| U2     | 5.67   | 5.80                      | 5.93  | 0.223 | 0.228       | 0.233 |

**Package Dimensions** 

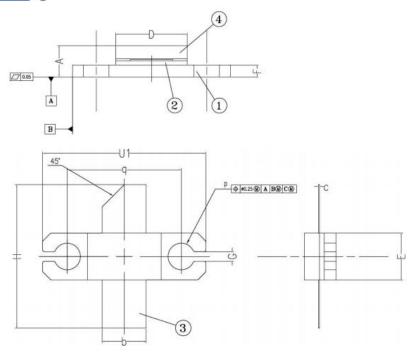
ACC0906S-4L Earless Flanged Air Cavity Ceramic Package; 2 Leads

# HTH7G14S150H(B)



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| C      | Dimesions in Milimeters |       | D     | imesions in Inch | es    |       |
|--------|-------------------------|-------|-------|------------------|-------|-------|
| Symbol | Min.                    | Mon.  | Max.  | Min.             | Mon.  | Max.  |
| A      | 3.84                    | 3.98  | 4,12  | 0.151            | 0.157 | 0.162 |
| b      | 5.37                    | 5.50  | 5.63  | 5.211            | 0.217 | 0.222 |
| c      | 0.11                    | 0.13  | 0.15  | 0.004            | 0.005 | 0.006 |
| D      | 9.07                    | 9.20  | 9.33  | 0.357            | 0.362 | 0.367 |
| E      | 5.67                    | 5.80  | 5.93  | 0.223            | 0.228 | 0.233 |
| F      | 1.37                    | 1.50  | 1.63  | 0.054            | 0.059 | 0.064 |
| G      | 1.07                    | 1.20  | 1.33  | 0.042            | 0.047 | 0.052 |
| Н      | 17.30                   | 17.80 | 18.30 | 0.681            | 0.701 | 0.720 |
| p      | 3.05                    | 3.3   | 3.55  | 0.120            | 0.130 | 0.140 |
| q      | 14.07                   | 14,20 | 14.33 | 0.554            | 0.559 | 0.564 |
| U1     | 20.17                   | 20.30 | 20.43 | 0.794            | 0.799 | 0.804 |

**Package Dimensions** 

ACC0906B-2L Flanged balanced Air Cavity Ceramic Package; 2 Leads; 2 Mounting Holes

Product datasheet



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## **Tape and Reel Information**

| Package Type | Qty/Tray(pcs) | Qty/Box(pcs) |
|--------------|---------------|--------------|
| ACC0906      | 30            | 300          |



**Packaging Descriptions** 

## **Handling Precautions**

| Parameter                      | Grade |
|--------------------------------|-------|
| Moisture Sensitivity Level MSL | 3     |

| Parameter                        | Rating    | Standard        |
|----------------------------------|-----------|-----------------|
| ESD – Human Body Model (HBM)     | Class 1B  | JESD22-A114     |
| ESD – Human Body Model (MM)      | Class A   | EIA/JESD22-A115 |
| ESD – Charged Device Model (CDM) | Class III | JESD22-C101     |



#### **RoHS Compliance**

This product is compliant with the 2011/65/EU RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment), as amended by Directive 2015/863/EU.

#### **Datasheet Status**

| Document status       | Product status    | Definition                                 |  |
|-----------------------|-------------------|--|--|
| Objective Datasheet   | Design simulation | Product objective specification            |  |
| Preliminary Datasheet | Customer sample   | Engineering samples and first test results |  |
| Product Datasheet     | Mass production   | Final product specification                |  |



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#### **Abbreviations**

| Acronym | Definition                                   |
|---------|--|
| LDMOS   | Laterally-Diffused Metal-Oxide Semiconductor |
| CW      | Continuous Waveform                          |

## **Revision history**

| Document ID | Datasheet Status | Release Date | Revision Version                              |
|-------------|------------------|--------------|---|
| Rev 2.2     | Product          | March 2023   | New format based on English version datasheet |
| Rev 2.3     | Product          | Sept. 2023   | Update TBD information                        |
| Rev 2.4     | Product          | March 2024   | Version released after re review              |

# WATECH

**Contact Information** 

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Product datasheet

For the latest specifications, additional product information, worldwide sales and distribution locations and information about WATECH:

• Web: www.watechelectronics.com

• Email: MKT@huatai-elec.com

For technical questions and application information:

• Email: MKT@huatai-elec.com

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